

KPGF-1011GBRC-120

1 x 1 x 0.2 mm Full-Color Surface Mount LED

DESCRIPTIONS

- The Green source color devices are made with InGaN on SiC substrate Light Emitting Diode
- The Blue source color devices are made with InGaN on SiC substrate Light Emitting Diode
- The Hyper-Red source color devices are made with AlGaInP on GaAs substrate Light Emitting Diode
- Electrostatic discharge and power surge could damage the LEDs
- It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs
- All devices, equipments and machineries must be electrically grounded

FEATURES

- 1.0 mm x 1.0 mm SMD LED, 0.2 mm thickness
- Low power consumption
- Package: 4000 pcs / reel
- Moisture sensitivity level: 3
- Halogen-free
- RoHS compliant

APPLICATIONS

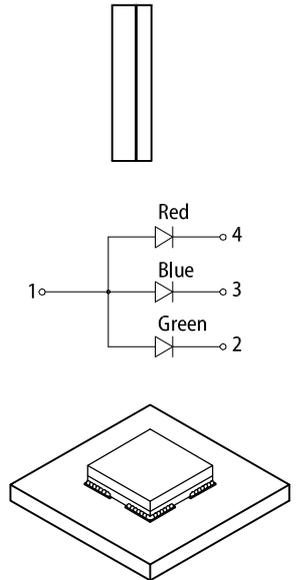
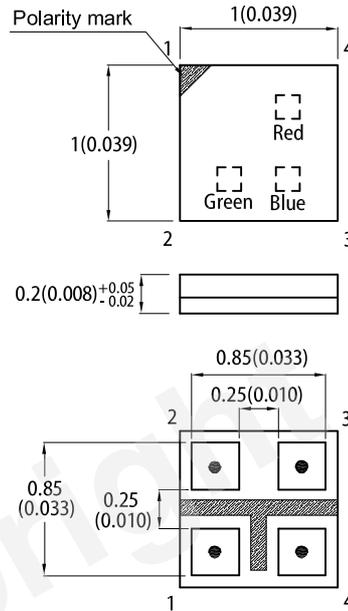
- Backlight
- Status indicator
- Home and smart appliances
- Wearable and portable devices
- Healthcare applications

ATTENTION

Observe precautions for handling
Electrostatic discharge sensitive devices

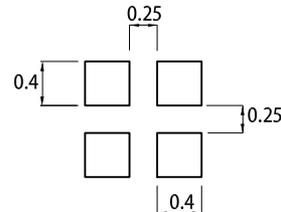


PACKAGE DIMENSIONS



RECOMMENDED SOLDERING PATTERN

(units : mm; tolerance : ± 0.1)



Mask open area ratio: 80%
Mask thickness: 80~100um

Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is ±0.1(0.004") unless otherwise noted.
3. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.
4. The device has a single mounting surface. The device must be mounted according to the specifications.

SELECTION GUIDE

Part Number	Emitting Color (Material)	Lens Type	Iv (mcd) @ 5mA ^[2]		Viewing Angle ^[1]
			Min.	Typ.	2θ1/2
KPGF-1011GBRC-120	■ Green (InGaN)	Water Clear	50	80	150°
	■ Blue (InGaN)		10	23	
	■ Hyper Red (AlGaInP)		15	30	

Notes:
1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 of the optical peak value.
2. Luminous intensity / luminous flux: +/-15%.
3. Luminous intensity value is traceable to CIE127-2007 standards.

ELECTRICAL / OPTICAL CHARACTERISTICS at T_A=25°C

Parameter	Symbol	Emitting Color	Value		Unit
			Typ.	Max.	
Wavelength at Peak Emission I _F = 5mA	λ _{peak}	Green Blue Hyper Red	518 461 632	-	nm
Dominant Wavelength I _F = 5mA	λ _{dom} [1]	Green Blue Hyper Red	527 467 624	-	nm
Spectral Bandwidth at 50% Φ REL MAX I _F = 5mA	Δλ	Green Blue Hyper Red	35 22 20	-	nm
Capacitance	C	Green Blue Hyper Red	100 110 25	-	pF
Forward Voltage I _F = 5mA	V _F [2]	Green Blue Hyper Red	3 2.9 1.95	3.2 3.1 2.3	V
Reverse Current (V _R = 5V)	I _R	Green Blue Hyper Red	-	50 50 10	μA
Temperature Coefficient of λ _{peak} I _F = 5mA, -10°C ≤ T ≤ 85°C	TC _{λpeak}	Green Blue Hyper Red	0.05 0.04 0.13	-	nm/°C
Temperature Coefficient of λ _{dom} I _F = 5mA, -10°C ≤ T ≤ 85°C	TC _{λdom}	Green Blue Hyper Red	0.03 0.03 0.06	-	nm/°C
Temperature Coefficient of V _F I _F = 5mA, -10°C ≤ T ≤ 85°C	TC _V	Green Blue Hyper Red	-3 -3 -1.9	-	mV/°C

Notes:

1. The dominant wavelength (λ_d) above is the setup value of the sorting machine. (Tolerance λ_d: ±1nm.)
2. Forward voltage: ±0.1V.
3. Wavelength value is traceable to CIE127-2007 standards.
4. Excess driving current and / or operating temperature higher than recommended conditions may result in severe light degradation or premature failure.

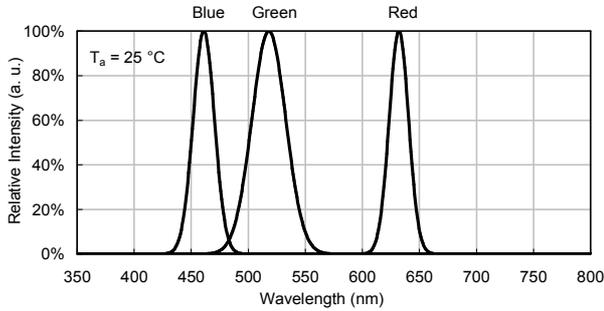
ABSOLUTE MAXIMUM RATINGS at T_A=25°C

Parameter	Symbol	Value			Unit
		Green	Blue	Hyper Red	
Power Dissipation	P _D [1]	35			mW
Reverse Voltage	V _R	5	5	5	V
Junction Temperature	T _j	125	125	115	°C
Operating Temperature	T _{op}	-40 to +85			°C
Storage Temperature	T _{stg}	-40 to +100			°C
DC Forward Current	I _F [2]	10	10	10	mA
Peak Forward Current	I _{FM} [3]	50	50	50	mA
Electrostatic Discharge Threshold (HBM)	-	1000	1000	3000	V
Thermal Resistance (Junction / Ambient)	R _{th JA} [4]	580	430	640	°C/W
Thermal Resistance (Junction / Solder point)	R _{th JS} [4]	440	330	500	°C/W

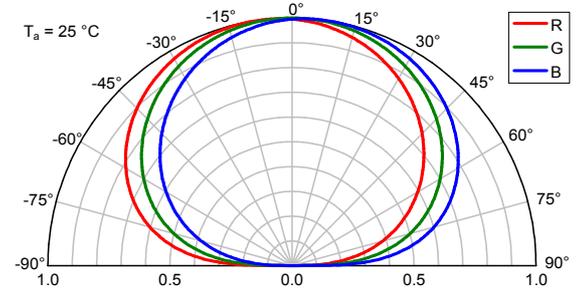
- Notes:
1. Within 35mW when multiple chips are lightened
 2. The maximum ratings are valid for the case of lighting a single chip
When two chips are lit at the same time, each chip should be driven at a current lower than 50% of the absolute maximum ratings
When three chips are lit at the same time, each chip should be driven at a current lower than 30% of the absolute maximum ratings
 3. Duty Cycle ≤ 1/20, Pulse Width = 1ms.
 4. R_{th JA}, R_{th JS} Results from mounting on PC board FR4 (pad size ≥ 16 mm² per pad).
 5. Relative humidity levels maintained between 40% and 60% in production area are recommended to avoid the build-up of static electricity – Ref JEDEC/JESD625-A and JEDEC/J-STD-033.

TECHNICAL DATA

RELATIVE INTENSITY vs. WAVELENGTH

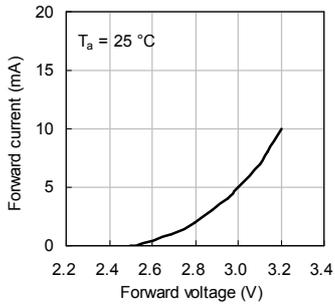


SPATIAL DISTRIBUTION

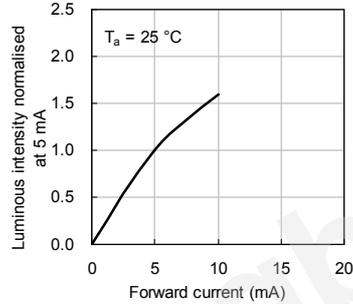


GREEN

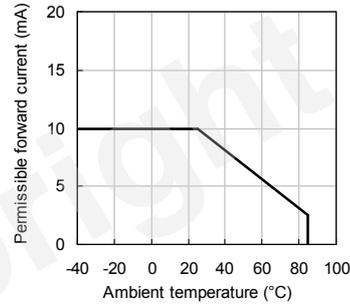
Forward Current vs. Forward Voltage



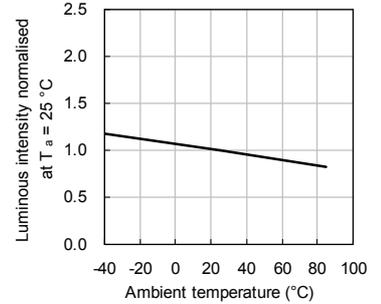
Luminous Intensity vs. Forward Current



Forward Current Derating Curve

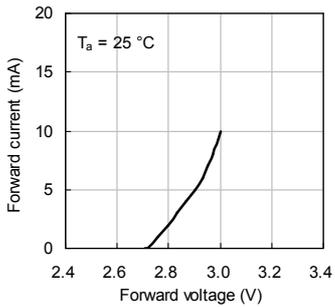


Luminous Intensity vs. Ambient Temperature

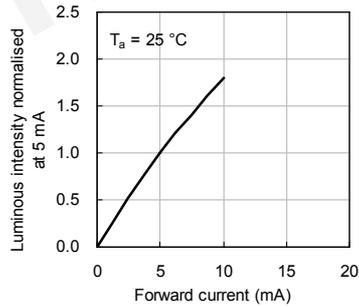


BLUE

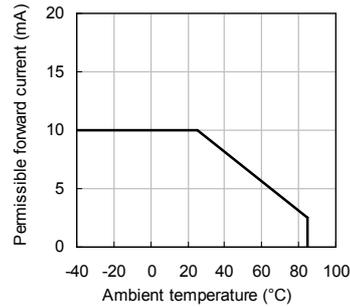
Forward Current vs. Forward Voltage



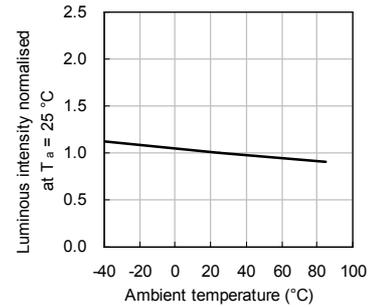
Luminous Intensity vs. Forward Current



Forward Current Derating Curve

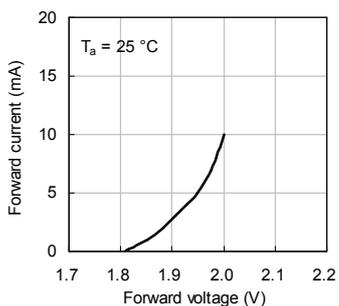


Luminous Intensity vs. Ambient Temperature

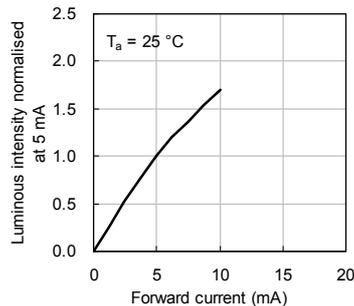


HYPER RED

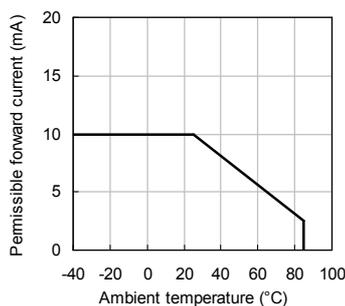
Forward Current vs. Forward Voltage



Luminous Intensity vs. Forward Current



Forward Current Derating Curve



Luminous Intensity vs. Ambient Temperature

